

Low-Power, High-Precision Operational Amplifier

FEATURES

- Supply Current 600 μ A Max
- OP-07 Type Performance
- Offset Voltage 25 μ V Max
- Offset Voltage Drift 0.6 μ V/ $^{\circ}$ C Max
- Very Low Bias Current 100pA Max
- Very Low Offset Current 100pA Max
- Low Noise 0.5 μ Vp-p
- Common Mode Rejection Ratio 114dB Min

APPLICATIONS

- Replaces OP-07 While Saving Power
- Precision Instrumentation
- Charge Integrators
- Wide Dynamic Range Logarithmic Amplifiers
- Light Meters
- Low Frequency Active Filters
- Thermocouple Amplifiers

DESCRIPTION

The OP-97 is a low-power precision amplifier that provides OP-07 performance while drawing less than 1/6 the OP-07 supply current. Offset voltage is 10 μ V and drift with temperature is 0.2 μ V/ $^{\circ}$ C.

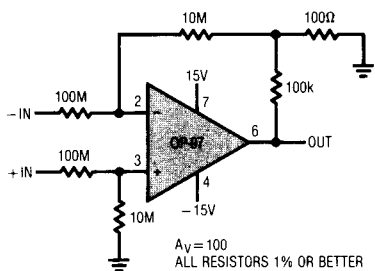
The OP-97 performance is improved over OP-07 performance in several areas. Bias and offset currents remain in the picoampere levels over the full military temperature range. Common mode voltage rejection and power supply rejection are also improved.

The OP-97 conforms to the OP-07 pinout with the null potentiometer connected between pins 1 and 8 with the wiper to V⁺. The OP-97 will upgrade circuit designs using 725, OP-05, OP-07 and OP-12 amplifiers.

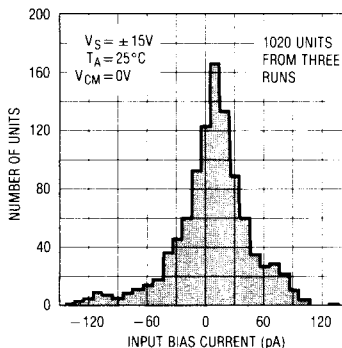
For applications requiring improved price and/or performance refer to the LT1012 and LT1097 datasheets.

Protected by U.S. patents 4,575,685 and 4,775,884

Instrumentation Amplifier with ± 100 V Common Mode Range



Typical Distribution of Input Bias Current



ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$\pm 20V$
Differential Input Current (Note 1)	$\pm 10mA$
Input Voltage	$\pm 20V$
Output Short Circuit Duration	Indefinite
Operating Temperature Range	
OP-97A	$-55^{\circ}C$ to $125^{\circ}C$
OP-97E	$-40^{\circ}C$ to $85^{\circ}C$
Storage Temperature Range	
All Devices	$-65^{\circ}C$ to $150^{\circ}C$
Lead Temperature (Soldering, 10 sec.)	$300^{\circ}C$

PACKAGE/ORDER INFORMATION

<p>TOP VIEW V_{OS} TRIM V_{OS} TRIM -IN +IN V- (CASE) H PACKAGE 8-LEAD TO-5 METAL CAN</p>	ORDER PART NUMBER
	OP-97AH OP-97EH
<p>TOP VIEW V_{OS} TRIM -IN +IN V- J8 PACKAGE 8-LEAD CERAMIC DIP</p> <p>N8 PACKAGE 8-LEAD PLASTIC DIP</p>	OP-97AJ8 OP-97EJ8 OP-97EN8

ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, V_{CM} = 0V, T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	OP-97A/E			UNITS
			MIN	TYP	MAX	
V_{OS}	Input Offset Voltage			10	25	μV
$\frac{\Delta V_{OS}}{\Delta Time}$	Long Term Offset Voltage Stability			0.3		$\mu V/$ Month
I_{OS}	Input Offset Current			30	100	pA
I_B	Input Bias Current			± 30	± 100	pA
e_n	Input Noise Voltage	0.1Hz to 10Hz		0.5		$\mu Vp-p$
	Input Noise Voltage Density	$f_o = 10Hz$ (Note 3) $f_o = 1000Hz$ (Note 4)		17 14	30 22	nV/ \sqrt{Hz} nV/ \sqrt{Hz}
i_n	Input Noise Current Density	$f_o = 10Hz$		20		fA/ \sqrt{Hz}
A_{VOL}	Large Signal Voltage Gain	$V_O = \pm 10V; R_L = 2k\Omega$	300	2000		V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13.5V$	114	132		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2V$ to $\pm 20V$	114	132		dB
	Input Voltage Range	(Note 2)	± 13.5	± 14.0		V
V_{OUT}	Output Voltage Swing	$R_L = 10k\Omega$	± 13	± 14		V
SR	Slew Rate		0.1	0.2		V/ μs
	Differential Input Resistance	(Note 5)	30			M Ω
	Closed-Loop Bandwidth	$A_{VCL} = +1$ (Note 5)	0.4	0.9		MHz
I_S	Supply Current			380	600	μA
V_S	Supply Voltage	Operating Range	± 2	± 15	± 20	V

ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$, $V_{CM} = 0V$, $-40^\circ C \leq T_A \leq 85^\circ C$ for the OP-97E and $-55^\circ C \leq T_A \leq 125^\circ C$ for the OP-97A unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	OP-97A/E			UNITS	
			MIN	TYP	MAX		
V_{OS}	Input Offset Voltage			25	60	μV	
TCV_{OS}	Average Temperature Coefficient of V_{OS}			0.2	0.6	$\mu V/^\circ C$	
I_{OS}	Input Offset Current			60	250	pA	
TCI_{OS}	Average Temperature Coefficient of I_{OS}			0.4	2.5	$pA/^\circ C$	
I_B	Input Bias Current	OP-97A		± 60	± 600	pA	
		OP-97E		± 60	± 250	pA	
TCI_B	Average Temperature Coefficient of I_B	OP-97A		0.4	6.0	$pA/^\circ C$	
		OP-97E		0.4	2.5	$pA/^\circ C$	
A_{VOL}	Large Signal Voltage Gain	$V_O = \pm 10V$; $R_L = 2k\Omega$		200	1000	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13.5V$		108	128	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.5V$ to $\pm 20V$		108	126	dB	
	Input Voltage Range	(Note 2)		± 13.5	± 14.0	V	
V_{OUT}	Output Voltage Swing	$R_L = 10k\Omega$		± 13	± 14	V	
SR	Slew Rate	(Note 6)		0.05	0.15	$V/\mu s$	
I_S	Supply Current			400	800	μA	
V_S	Supply Voltage	Operating Range		± 2.5	± 15	± 20	V

The ● denotes the specifications which apply over the full operating temperature range.

Note 1: Differential input voltages greater than 1V will cause excessive current to flow through the input protection diodes unless limiting resistance is used.

Note 2: Guaranteed by CMRR test.

Note 3: 10Hz noise voltage density is sample tested. Devices 100% tested for noise are available on request.

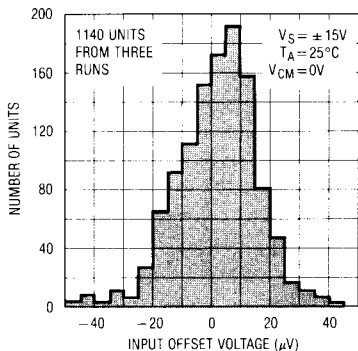
Note 4: Sample tested.

Note 5: Guaranteed by design.

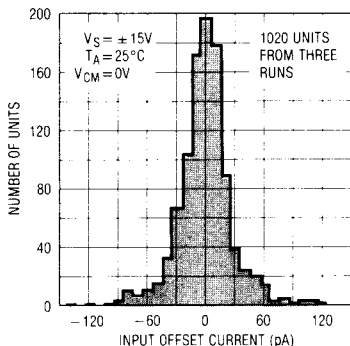
Note 6: Guaranteed by design and correlation to 25°C limit.

TYPICAL PERFORMANCE CHARACTERISTICS

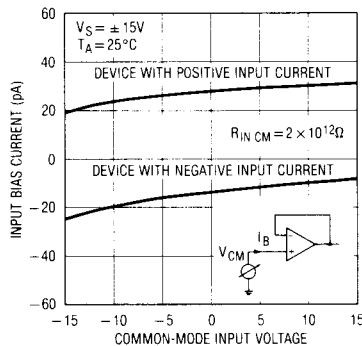
Typical Distribution of Input Offset Voltage



Typical Distribution of Input Offset Current

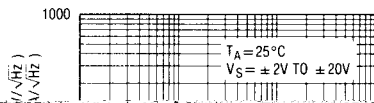


Input Bias Current Over Common Mode Range

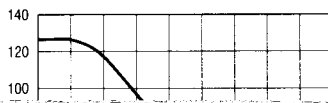


TYPICAL PERFORMANCE CHARACTERISTICS

Noise Spectrum



Voltage Gain vs Frequency



Gain, Phase Shift vs Frequency

